TOSHIBA Field Effect Transistor Silicon P Channel MOS Type (U-MOSV)

TPC6111

Notebook PC Applications Portable Equipment Applications

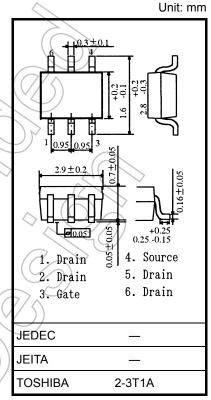
• Low drain-source ON resistance: RDS (ON) = 33 m Ω (typ.)

• Low leakage current: $I_{DSS} = -10 \mu A \text{ (max) (V}_{DS} = -20 \text{ V)}$

• Enhancement mode: V_{th} = -0.3 to -1.0 V (V_{DS} = -10 V, I_{D} = -1mA)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Drain-source voltage		V_{DSS}	-20	(Y)	
Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$)		V_{DGR}	-20	(\sqrt{v})	
Gate-source voltage			V_{GSS}	±8	A
Drain current	DC (I	Note 1)	ΙD	-5.5	A
	Pulse (i	Note 1)	I_{DP}	-22	> A
Drain power dissipation (t = 5 s) (Note 2a)			P_{D}	2.2	W
Drain power dissipation (t = 5 s) (Note 2b)		PD	0.7	W	
Single pulse avalanche energy (Note 3)			EAS	5.1	βŽ
Avalanche current		I _{AR}	<i>─</i> 2.8	Α	
Repetitive avalanche energy (Note 4)		EAR	0.019	mJ	
Channel temperature			Tch	150	7,6
Storage temperature range			√T _{stg}	-55~150)°C



Weight: 0.011 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

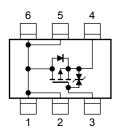
Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to ambient $(t = 5 s)$ (Note 2a)	R _{th (ch-a)}	56.8	°C/W
Thermal resistance, channel to ambient $(t = 5 \text{ s})$ (Note 2b)	R _{th (ch-a)}	178.5	°C/W

Note: (Note 1), (Note 2), (Note 3), (Note 4) and (Note 5): See other pages.

This transistor is an electrostatic-sensitive device. Please handle with caution.

Circuit Configuration



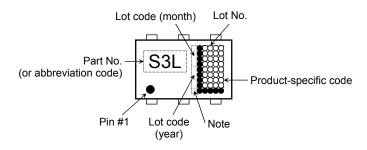
Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GSS}	$V_{GS} = \pm 8 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±1	μА
Drain cut-off current		I _{DSS}	$V_{DS} = -20 \text{ V}, V_{GS} = 0 \text{ V}$	_	_	-10	μА
Drain-source breakdown voltage		V (BR) DSS	$I_D = -10 \text{ mA}, V_{GS} = 0 \text{ V}$	-20	_	_	V
		V (BR) DSX	$I_D = -10 \text{ mA}, V_{GS} = 8 \text{ V}$	-12	_	_	V
Gate threshold vo	oltage	V _{th}	$V_{DS} = -10 \text{ V}, I_D = -1 \text{mA}$	-0.3) /_	-1.0	V
Drain-source ON resistance		R _{DS (ON)}	V _{GS} = -1.5 V, I _D = -1.4 A) 	76	150	- mΩ
		R _{DS} (ON)	$V_{GS} = -1.8 \text{ V}, I_D = -1.4 \text{ A}$)	56	80	
		R _{DS} (ON)	V _{GS} = -2.5 V, I _D = -2.8 A		44	57	
		R _{DS} (ON)	V _{GS} = -4.5 V, I _D = -2.8 A	_	33	40	
Forward transfer	Forward transfer admittance		$V_{DS} = -10 \text{ V}, I_D = -2.8 \text{ A}$	7	14	_	S
Input capacitance		C _{iss}			700	\rightarrow	
Reverse transfer capacitance		C _{rss}	$V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	-6	100	> —	pF
Output capacitance		Coss		7-6	140) —	
Switching time	Rise time	t _r	0 V T I _D = -2.8 A	7	57	_	
	Turn-on time	t _{on}	VGS 0 V ID = -2.6 A O VOUT	2)	12	_	
	Fall time	t _f	H = 3.6) —	30	_	ns
	Turn-off time	toff	V _{DD} ≈ −10 V Duty ≤ 1%, t _W = 10 μs	_	95	_	
Total gate charge (gate-source plus gate-drain)		Qg)	$V_{DD} \approx -16 \text{ V, } V_{GS} = -5 \text{ V,}$	_	10	_	
Gate-source charge 1		Q _{gs} 1	$I_D = -5.5 \text{ A}$	_	1.2	_	nC
Gate-drain ("miller") charge		(_	2.5	_	

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics Symbol Test Condition	Min	Тур.	Max	Unit
Drain reverse current Pulse (Note 1) I _{DRP} —	_	_	-22	Α
Forward voltage (diode) $V_{DSF} > I_{DR} = -5.5 \text{ A}, V_{GS} = 0 \text{ V}$	_	_	1.2	V

Marking (Note 5)



Note: A dot marking for identifying the indication of product Labels.

Without a dot: [[Pb]]/INCLUDES > MCV

With a dot: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

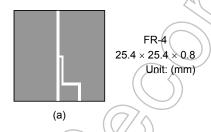
Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.

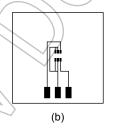
The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: (a) Device mounted on a glass-epoxy board (a) (t = 5 s)

(b) Device mounted on a glass-epoxy board (b) (t = 5 s)





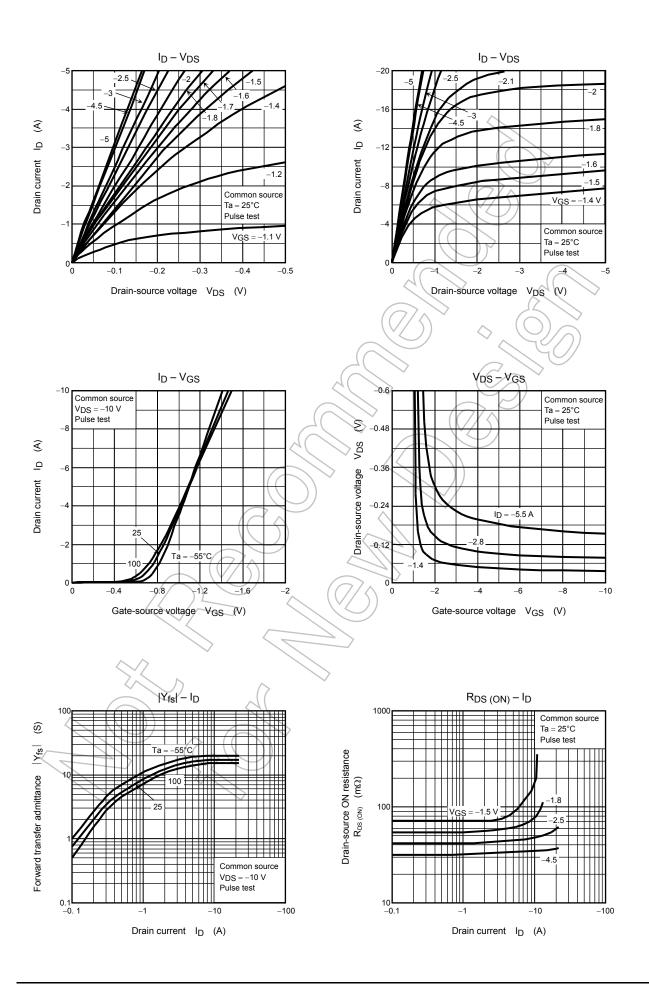
FR-4 $25.4 \times 25.4 \times 0.8$ Unit: (mm)

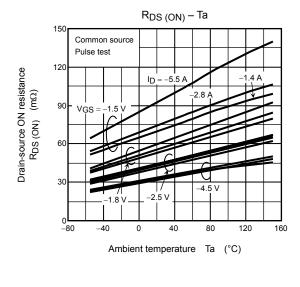
Note 3: $V_{DD} = -16 \text{ V}$, $T_{ch} = 25^{\circ}\text{C}$ (initial), L = 0.5 mH, $R_G = 25 \Omega$, $I_{AR} = -2.8 \text{ A}$

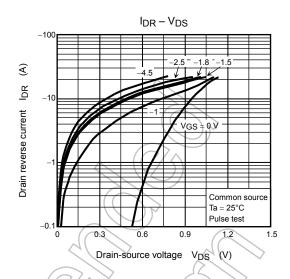
Note 4: Repetitive rating;:pulse width limited by maximum channel temperature

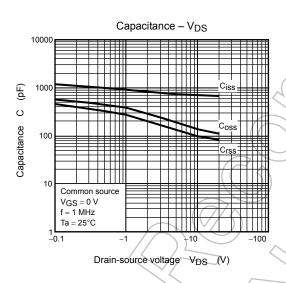
Note 5: • on lower left of the marking indicates Pin 1.

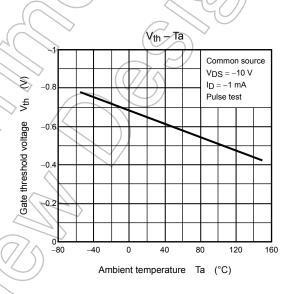


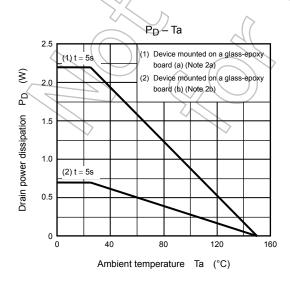


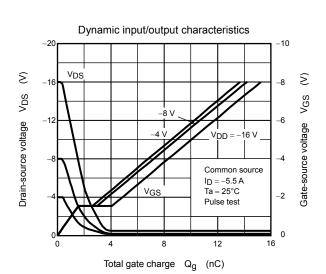




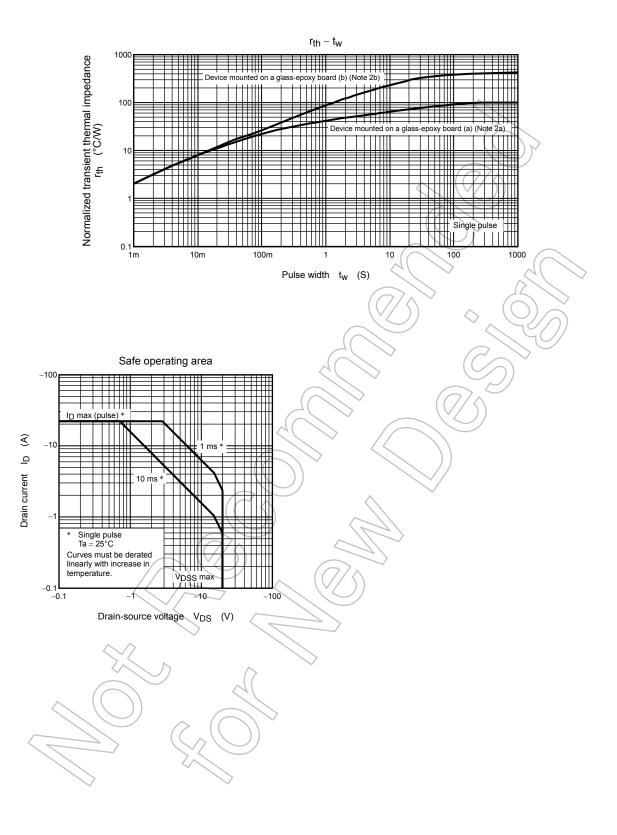








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